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Vishay Semiconductors

AUTOMOTIVE GRADE

RoHS

COMPLIANT

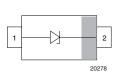
HALOGEN

**FREE** 

GREEN

(5-2008)

# Single ESD-Protection Diode in SOD-523





### **MARKING** (example only)



Bar = cathode marking X = date code

Y = type code (see table below)

#### **ADDITIONAL RESOURCES**



#### **FEATURES**

- Compact SOD-523 package
- Low package height < 0.7 mm
- 1-line ESD-protection
- AEC-Q101 qualified available
- Working range 0 V to 5 V
- Low leakage current I<sub>R</sub> < 0.1 μA</li>
- Surge current 16 A (at 8/20 μs)
- ESD-protection acc. IEC 61000-4-2
  - ± 30 kV contact discharge
  - ± 30 kV air discharge
- e3 Sn

Tin plated exposed side wall of lead frame

- Soldering can be checked by standard vision inspection
- AOI = Automated Optical Inspection
- No X-ray necessary
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912">www.vishay.com/doc?99912</a>

ORDERING INFORMATION							
	AEC-Q101 QUALIFIED	ENVIRON					
PART NUMBER (EXAMPLE)		RoHS COMPLIANT + LEAD (Pb)-FREE TERMINATIONS	TIN PLATED	8K PER 7" REEL (8 mm TAPE)	ORDERING CODE (EXAMPLE)		
		GREEN		MOQ = 8K/BOX			
VESD05A1-02V	=	G	3	-08	VESD05A1-02V-G3-08		
VESD05A1-02V	Н	G	3	-08	VESD05A1-02VHG3-08		

PACKAGE DATA							
DEVICE NAME	PACKAGE NAME	TYPE CODE	WEIGHT	MOLDING COMPOUND FLAMMABILITY RATING	MOISTURE SENSITIVITY LEVEL	SOLDERING CONDITIONS	
VESD05A1-02V (-G3-08 / HG3-08)	SOD-523	. Н	1.32 mg	UL 94 V-0	MSL level 1 (according J-STD-020)	Peak temperature max. 260 °C	

ABSOLUTE MAXIMUM RATINGS						
PARAMETER	TEST CONDITIONS	SYMBOL	VALUE	UNIT		
Peak pulse current	Acc. IEC 61000-4-5, 8/20 μs/single shot	I <sub>PPM</sub>	16	А		
Peak pulse power	Acc. IEC 61000-4-5, 8/20 μs/single shot	P <sub>PP</sub>	192	W		
ECD immunity	Contact discharge acc. IEC 61000-4-2; 10 pulses	W	± 30	kV		
ESD immunity	Air discharge acc. IEC 61000-4-2; 10 pulses	V <sub>ESD</sub>	± 30	kV		
Operating temperature	rating temperature Junction temperature		-55 to +150	°C		
Storage temperature		T <sub>stg</sub>	-55 to +150	°C		



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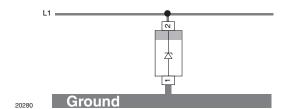
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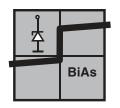
#### **BiAs-MODE** (bidirectional asymmetrical protection mode)

With the VESD05A1-02V one signal- or data-lines (L1) can be protected against voltage transients. With pin 1 connected to ground and pin 2 connected to a signal- or data-line which has to be protected. As long as the voltage level on the data- or signal-line is between 0 V (ground level) and the specified maximum reverse working voltage ( $V_{RWM}$ ) the protection diode between data line and ground offers a high isolation to the ground line. The protection device behaves like an open switch. As soon as any positive transient voltage signal exceeds the break through voltage level of the protection diode, the diode becomes conductive and shorts the transient current to ground. Now the protection device behaves like a closed switch. The clamping voltage ( $V_C$ ) is defined by the breakthrough voltage ( $V_{BR}$ ) level plus the voltage drop at the series impedance (resistance and inductance) of the protection device.

Any negative transient signal will be clamped accordingly. The negative transient current is flowing in the forward direction of the protection diode. The low forward voltage (V<sub>F</sub>) clamps the negative transient close to the ground level.

Due to the different clamping levels in forward and reverse direction the VESD05A1-02V clamping behaviour is bidirectional and asymmetrical (BiAs).





<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITIONS/REMARKS	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Protection paths	Number of lines which can be protected	N <sub>channel</sub>	-	-	1	lines		
Reverse stand off voltage	Max. reverse working voltage	$V_{RWM}$	-	-	5	V		
Reverse voltage	at I <sub>R</sub> = 1 μA	$V_R$	5	-	-	V		
Reverse current	at V <sub>R</sub> = 5 V	I <sub>R</sub>	-	< 0.1	1	μA		
Reverse breakdown voltage	at I <sub>R</sub> = 1 mA	$V_{BR}$	6	6.8	7.5	V		
Devenue elemenine veltere	at I <sub>PP</sub> = 1 A; 8/20 µs test pulse	V <sub>C</sub>	-	7.2	8.5	V		
Reverse clamping voltage	at I <sub>PP</sub> = I <sub>PPM</sub> = 16 A; 8/20 µs test pulse	V <sub>C</sub>	-	10.5	12	V		
	at I <sub>PP</sub> = 0.2 A; 8/20 µs test pulse	$V_{F}$	-	0.88	1.1	V		
Forward clamping voltage	at I <sub>PP</sub> = 1 A; 8/20 µs test pulse	V <sub>F</sub>	-	1	1.5	V		
	at I <sub>PP</sub> = I <sub>PPM</sub> = 16 A; 8/20 µs test pulse	V <sub>F</sub>	-	3.2	4.5	V		
Canacitance	at $V_R = 0 V$ ; $f = 1 MHz$	C <sub>D</sub>	-	130	150	pF		
Capacitance	at V <sub>R</sub> = 2.5 V; f = 1 MHz	C <sub>D</sub>	-	76	-	pF		



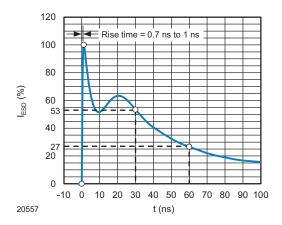


Fig. 1 - ESD Discharge Current Wave Form acc. IEC 61000-4-2 (330  $\Omega$  / 150 pF)

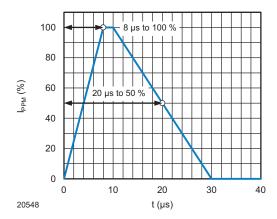


Fig. 2 - 8/20µs Peak Pulse Current Wave Form acc. IEC 61000-4-5

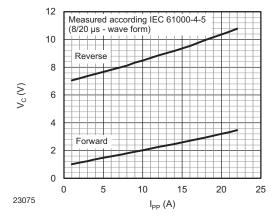


Fig. 3 - Typical Peak Clamping Voltage vs. Peak Pulse Current

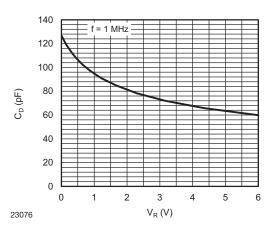


Fig. 4 - Typical Capacitance vs. Reverse Voltage

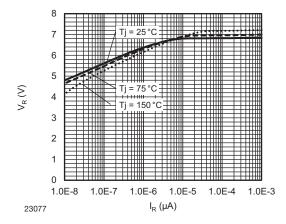


Fig. 5 - Typical Reverse Voltage vs. Reverse Current

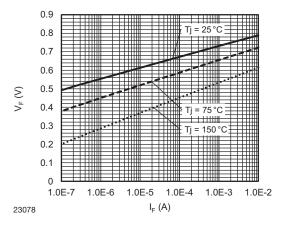


Fig. 6 - Typical Forward Voltage vs. Forward Current

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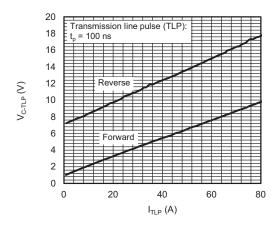
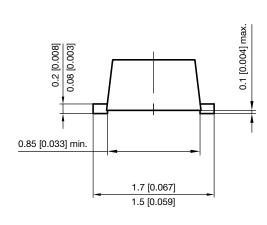
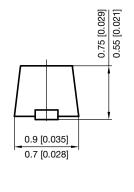
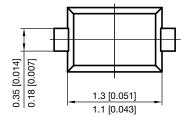


Fig. 7 - Typical Clamping Voltage vs. Peak Pulse Current

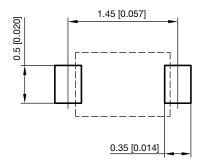
### PACKAGE DIMENSIONS in millimeters (inches): SOD-523







foot print recommendation:



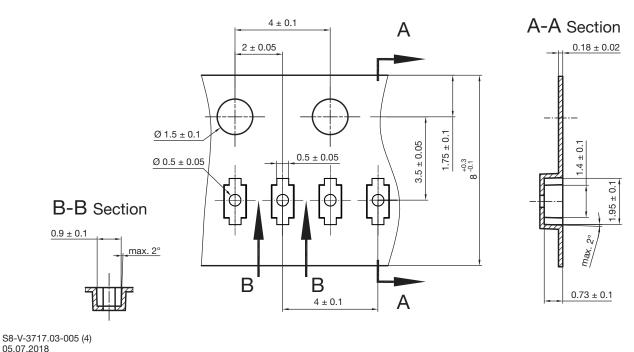
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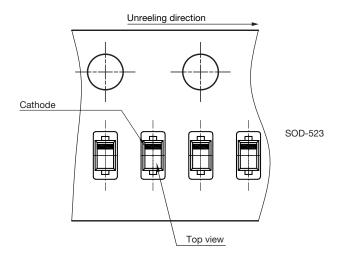


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### **CARRIER TAPE SOD-523**



### **ORIENTATION IN CARRIER TAPE SOD-523**



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